General Description

The ULN2003Ais high-voltage high-current Darlington transistor arrays each containing seven open collecto rcommon emitter pairs. Each pair is rated at 500mA. Suppression diodes are included for inductive load driv -ing, the inputs and outputs are pinned in opposition to simplify board layout.

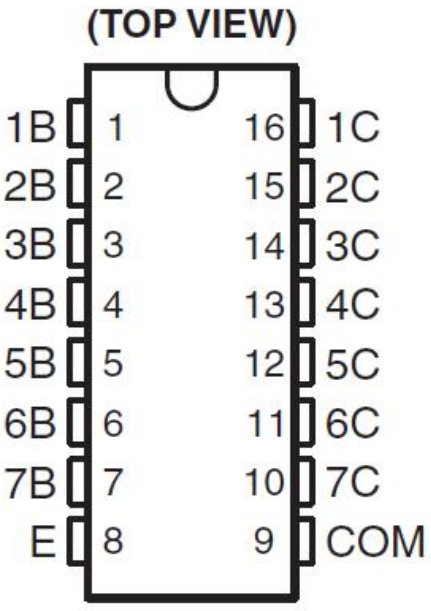
These devices are capable of driving a wide range of loads including solenoids, relays, DC motors, LED displays,filament lamps, thermal print-heads and high-power buffers.

The ULN2003A is available in both a small outline 16-pin package (DIP-16, SOP16 , TSSOP16).

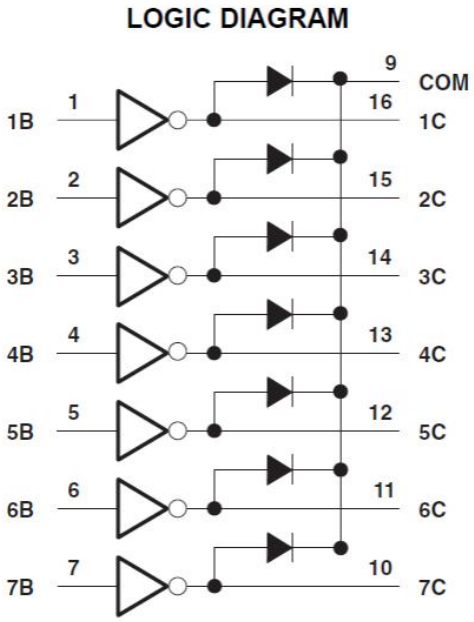
Features

- 500-mA-Rated Collector Current(single output)
- High-Voltage Outputs:50V
- Output Clamp Diodes
- Inputs Compatible With Various Types of Logic
- Relay-Driver Applications

Encapsulation form and pin definition function

Pin Assignments	Marking
	ULN2003 ******* SOP-16
	**** ULN2003A TSSOP16
	ULN2003AN ******* DIP-16

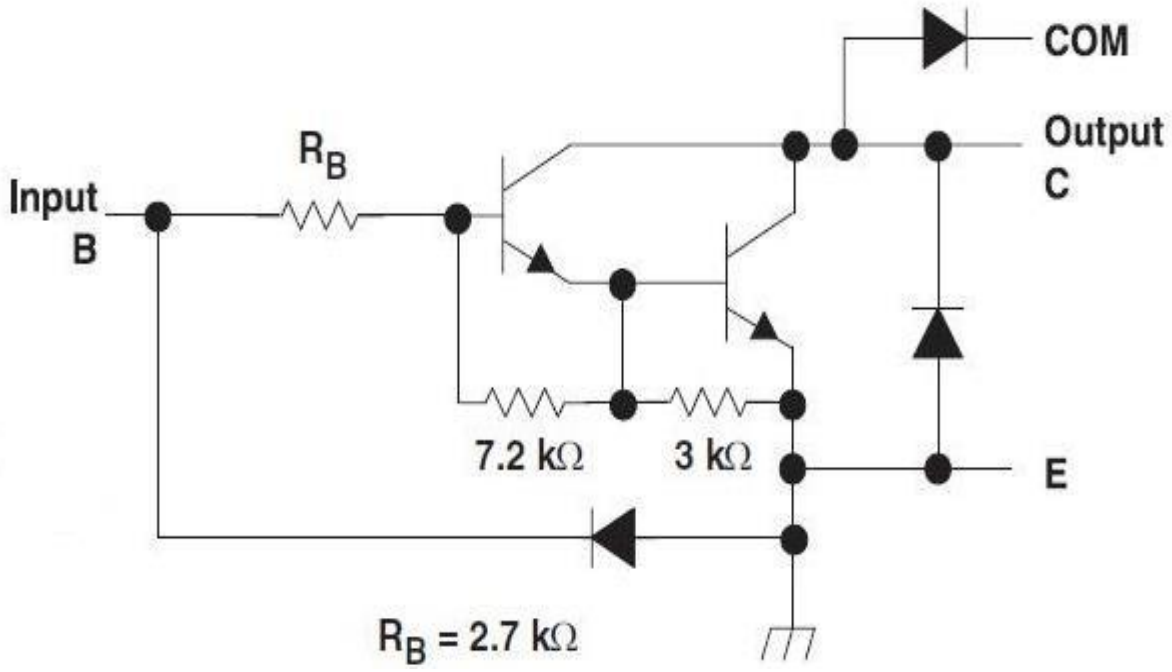
Connection Diagram



Pin Descriptions

Pin Number	Pin Name	Function
1	1B	Input pair1
2	2B	Input pair1
3	3B	Input pair1
4	4B	Input pair1
5	5B	Input pair1
6	6B	Input pair1
7	7B	Input pair1
8	E	Common Emitter (ground)
9	COM	Common Clamp Diodes
10	7C	Output pair7
11	6C	Output pair6
12	5C	Output pair5
13	4C	Output pair4
14	3C	Output pair3
15	2C	Output pair2
16	1C	Output pair1

Functional Block Diagram



Note: All resistor values shown are nominal.

The collentor-emitter diode is a parasitic structure and should not be used to conduct current.If the collector(s) go below ground an external Schoottky diode should be added to clamp negative undershoots.

Order Information

Designator	Package	Packing type
ULN2003	SOP-16	3500
ULN2003APWR	TSSOP16	4000
ULN2003AN	DIP-16	25

Absolute Maximum Ratings (1)

At 25°C free-air temperature (unless otherwise noted)

Symbol	Parameter		Min	Max	Unit
V_{CC}	Collector to emitter voltage			50	V
V_R	Clamp diode reverse voltage(2)			50	V
V_I	Input voltage(2)			30	V
I_{CP}	Peak collector current	See typical characteristics		500	mA
I_{OK}	Output clamp current			500	mA
I_{TE}	Total emitter-terminal current			-2.5	A
T_A	Operating free-air temperature range	ULN2003Axxx-MS	-40	+105	°C
θ_{JA}	Thermal Resistance Junction-to-Ambient(3)			63	°C/W
θ_{JC}	Thermal Resistance Junction-to-Case(4)			12	
TJ	Operating virtual junction temperature			+150	°C
T_{STG}	Storage temperature range		-65	+150	°C
ESD	Human Body Mode		--	3000	V

(1) =Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device.

These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated

conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.

(3) Maximum power dissipation is a function of TJ(max), θJA, and TA. The maximum allowable power dissipation at any allowable ambient temperature is PD = (TJ(max) – TA)/θJA. Operating at the absolute maximum TJ of 150°C can affect reliability.

(4) Maximum power dissipation is a function of TJ(max), θJC, and TA. The maximum allowable power dissipation at any allowable ambient temperature is PD = (TJ(max) – TA)/θJC. Operating at the absolute maximum TJ of 150°C can affect reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
VCC	Collector to Emitter voltage	-	50	V
TA	Operating Ambient Temperature	-40	+85	℃

Electrical Characteristics(TA=+25℃, unless otherwise specified)

Parameter		Test Figure	Test Conditions		ULN2003A MIN	ULN2003A TYP	ULN2003A MAX	Unit
$V_{I(on)}$	On-state input voltage	Figure 6	VCE = 2 V	IC = 200 mA	--	--	2.4	V
				IC = 250 mA	--	--	2.7	
				IC = 300 mA	--	--	3	
$V_{CE(sat)}$	Collector-emitter saturation voltage	Figure 5	II = 250 μA,	IC = 100 mA	--	0.9	1.1	
			II = 350 μA,	IC = 200 mA	--	1	1.3	V
			II = 500 μA,	IC = 350 mA	--	1.2	1.6	
I_{CEX}	Collector cutoff current	Figure 1	VCE = 50 V,	II = 0	--	--	50	μA
		Figure 2	VCE = 50 V, TA = +105°C	II = 0	--	--	100	
V_F	Clamp forward voltage	Figure 8	IF = 350 mA		--	1.7	2	V
$I_{I(off)}$	Off-state input current	Figure 3	VCE = 50 V,	IC = 500 μA	50	65	--	μA
II	Input current	Figure 4	VI = 3.85 V		--	0.93	1.35	mA
			VI = 5 V		--	--	--	
			VI = 12 V		--	--	--	
IR	Clamp reverse current	Figure 7	VR = 50 V		--	--	50	μA
				TA = 70°C	--	--	100	
Ci	Input capacitance		VI = 0,	f = 1 MHz	--	15	25	pF

Switching Characteristics (TA = +25°C, unless otherwise specified)

Parameter		Test Conditions	ULN2003A MIN	ULN2003A TYP	ULN2003A MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	See Figure 9		0.25	1	μs
t_{PHL}	Propagation delay time, high- to low-level output	See Figure 9		0.25	1	μs
V_{OH}	High-level output voltage after switching	VS = 50 V, IO = 300 mA, See Figure 9	VS–20			mV

ParameterMeasurementInformation

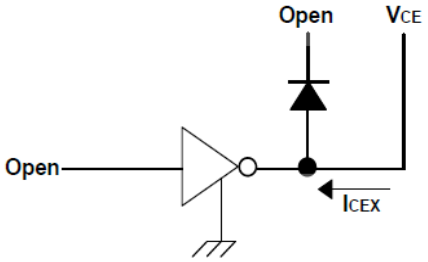


Fig.1 I_{CEX} Test Circuit

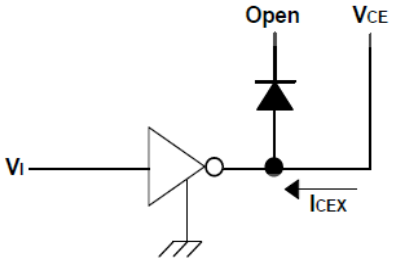


Fig.2 I_{CEX} Test Circuit

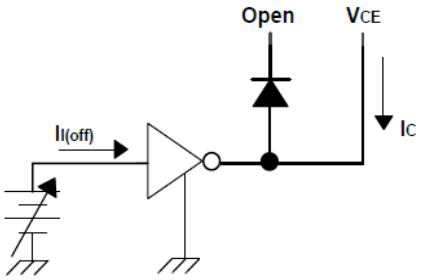


Fig.3 $I_{I(off)}$ Test Circuit

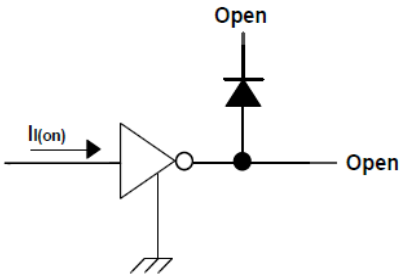


Fig.4 I_I Test Circuit

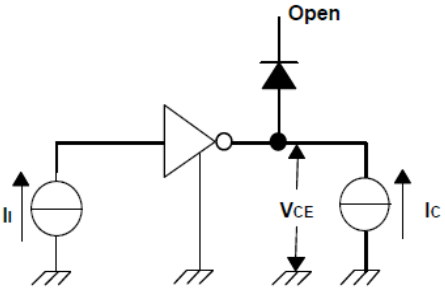


Fig. 5 h_{FE} , $V_{CE(sat)}$ Test Circuit

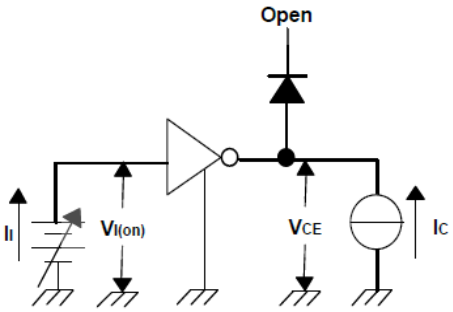


Fig. 6 $V_{I(on)}$ Test Circuit

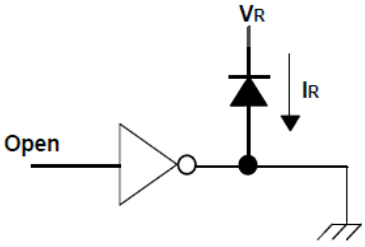


Fig. 7 I_R Test Circuit

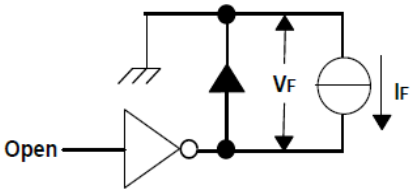
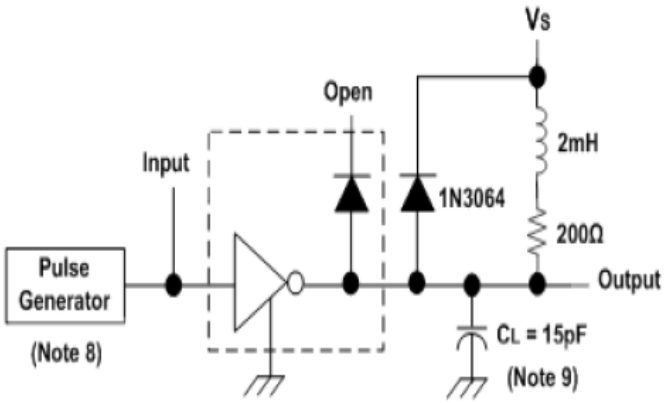
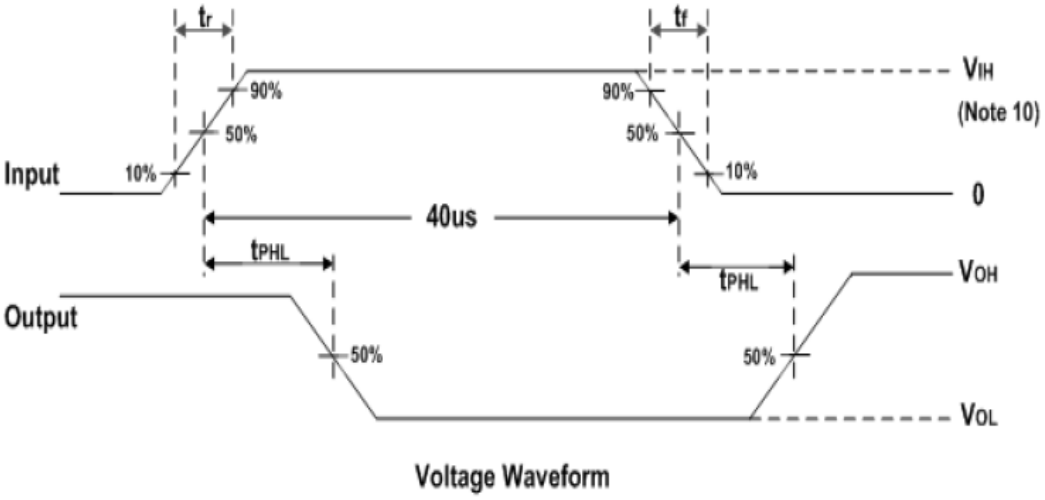


Fig. 8 V_F Test Circuit



t_{ON}, t_{OFF} Test Circuit



Voltage Waveform

Fig. 9 Latch-Up Test Circuit and Voltage Waveform

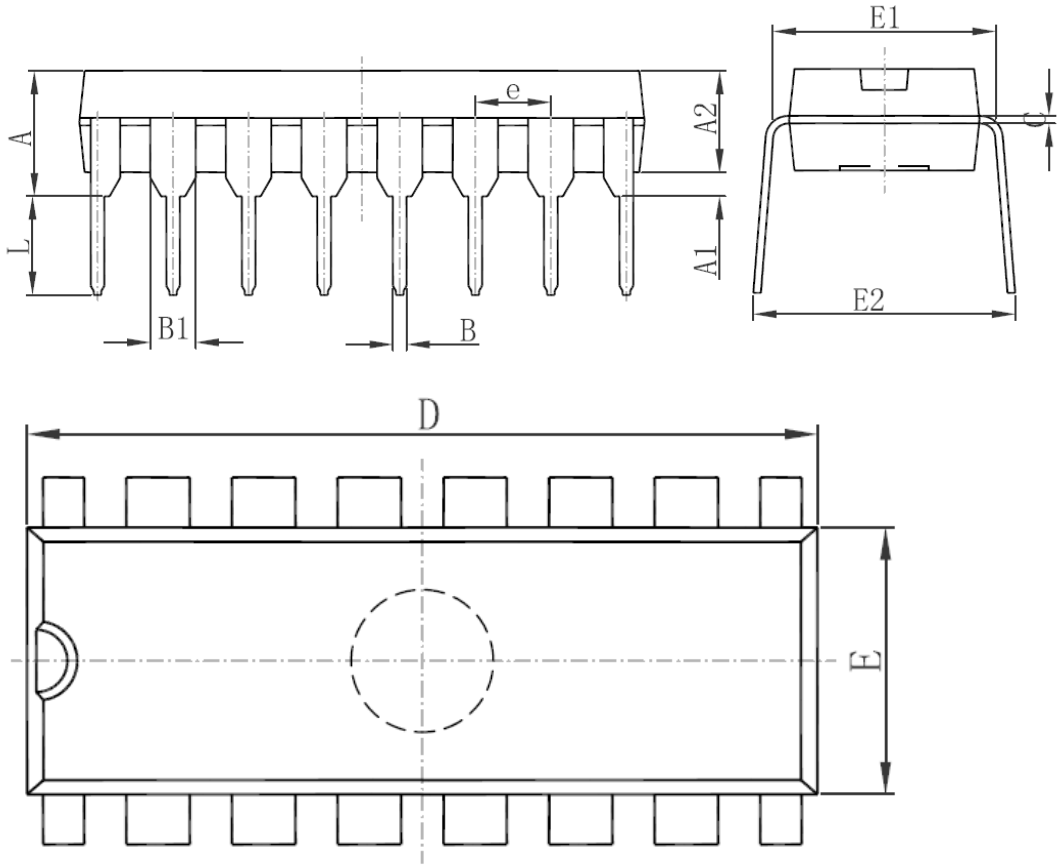
Notes: 8. The pulse generator has the following characteristics:

Pulse Width=12.5Hz, output impedance 50Ω, tr≤5ns, tr≤10ns.

9. C_L includes prove and jig capacitance.

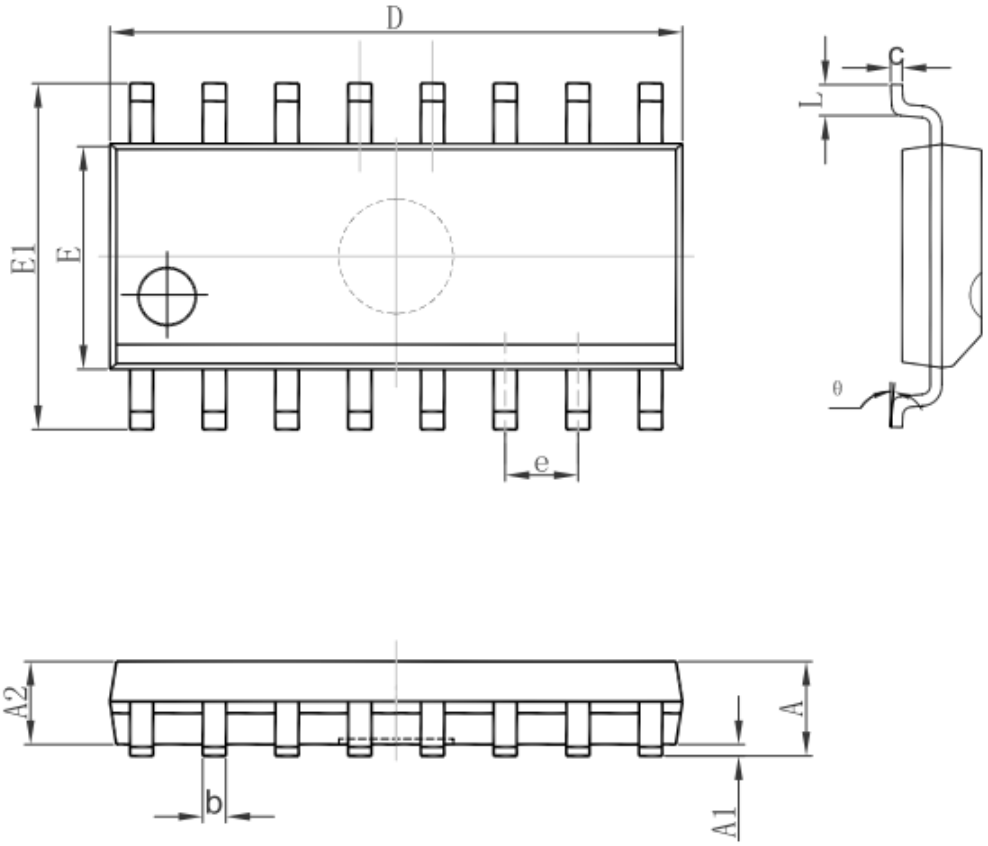
10. V_{IH}=3V

DIP-16Outline Dimensions



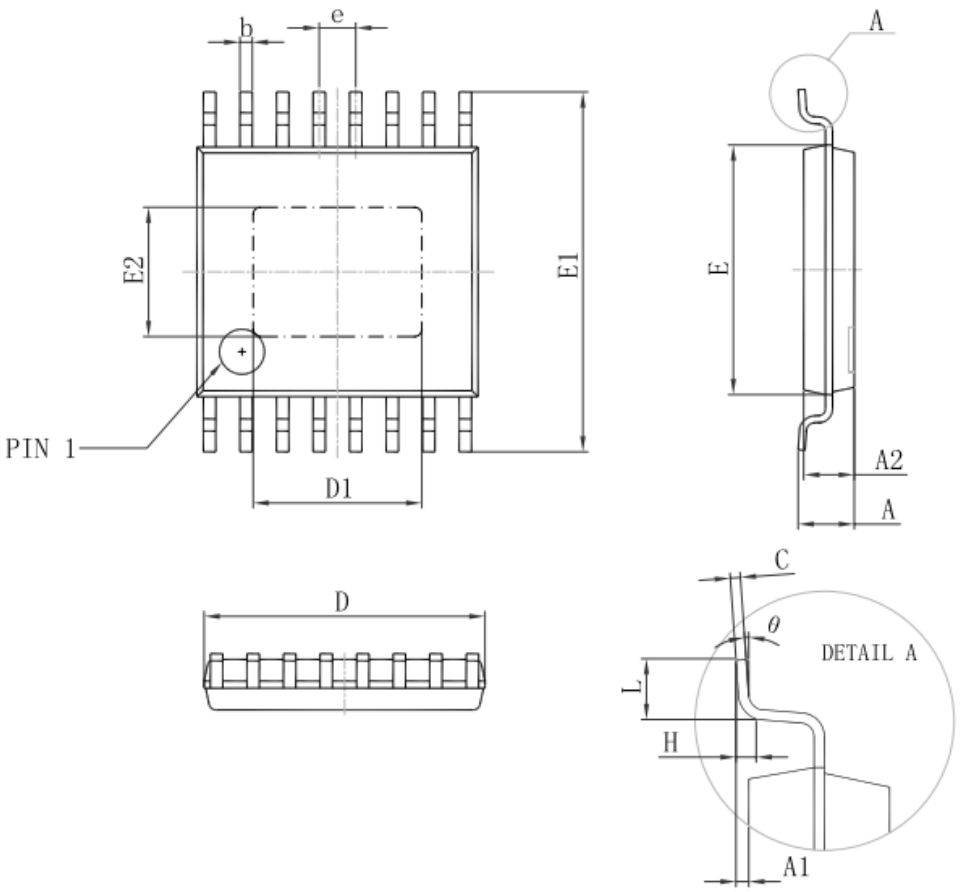
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.710	4.310	0.146	0.170
A1	0.510		0.020	
A2	3.200	3.600	0.126	0.142
B	0.380	0.570	0.015	0.022
B1	1.524(BSC)		0.060(BSC)	
C	0.204	0.360	0.008	0.014
D	18.800	19.200	0.740	0.756
E	6.200	6.600	0.244	0.260
E1	7.320	7.920	0.288	0.312
e	2.540(BSC)		0.100(BSC)	
L	3.000	3.600	0.118	0.142
E2	8.400	9.000	0.331	0.354

SOP-16 Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	9.800	10.200	0.386	0.402
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

TSSOP16 Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	**Max**	**Min**	**Max**
D	4.900	5.100	0.193	0.201
D1	2.900	3.100	0.114	0.122
E	4.300	4.500	0.169	0.177
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
E1	6.250	6.550	0.246	0.258
E2	2.200	2.400	0.087	0.094
A		1.150		0.043
A2	0.800	1.000	0.031	0.039
A1	0.020	0.150	0.001	0.006
e	0.65 (BSC)		0.026(BSC)	
L	0.500	0.700	0.02	0.028
H	0.25(TYP)		0.01(TYP)	
θ	1°	7°	1°	7°